

BOX PCT

IN THE UNITED STATES DESIGNATED/ELECTED OFFICE
OF THE UNITED STATES PATENT AND TRADEMARK OFFICE
UNDER THE PATENT COOPERATION TREATY-CHAPTER II

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AMENDMENT "A" PRIOR TO ACTION

APPLICANT(S): Thomas Aeugle et al.
ATTORNEY DOCKET NO.: P99,1696
INTERNATIONAL APPLICATION NO.: PCT/EP98/01405
INTERNATIONAL FILING DATE: 11 March 1998

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INVENTION: "METHOD FOR THE PRODUCTION OF A
VERTICAL MOS TRANSISTOR"

Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

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Applicants herewith amend the above-referenced PCT application,
and request entry of the Amendment prior to examination on the United
States National Examination Phase.

IN THE DRAWINGS:

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Please amend Figures 1, 2 and 13, as shown on the drawing
copies marked in red, attached to the Request for Approval of Drawing
Changes, filed simultaneously herewith.

IN THE SPECIFICATION:

On page 1, cancel the title above line 5, and insert the following
above line 5:

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--TITLE

METHOD FOR THE PRODUCTION OF A VERTICAL MOS
TRANSISTOR

BACKGROUND OF THE INVENTION

The present invention relates to a method for the production of a

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